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REVISION HISTORY

11/06—Revision 0: Initial Version

SPECIFICATIONS

$V_{DD} = 5\text{ V} \pm 10\%$, $GND = 0\text{ V}$. Temperature range for the B version is -40°C to $+85^{\circ}\text{C}$, unless otherwise noted.

Table 1.

Parameter	B Version		Unit	Test Conditions/Comments
	+25°C	–40°C to +85°C		
ANALOG SWITCH				
Analog Signal Range		0 V to V _{DD}	V	V _S = 0 V to V _{DD} , I _S = –10 mA; see Figure 12
On Resistance (R _{ON})	2		Ω typ	
	3	4	Ω max	V _S = 0 V to V _{DD} , I _S = –10 mA
On Resistance Flatness (R _{FLAT(ON)})	0.5		Ω typ	
		1.0	Ω max	
LEAKAGE CURRENTS				
Source Off Leakage, I _S (OFF)	±0.01		nA typ	V _{DD} = 5.5 V
	±0.25	±0.35	nA max	V _S = 4.5 V/1 V, V _D = 1 V/4.5 V; see Figure 13
Drain Off Leakage, I _D (OFF)	±0.01		nA typ	V _S = 4.5 V/1 V, V _D = 1 V/4.5 V; see Figure 13
	±0.25	±0.35	nA max	
Channel On Leakage, I _D , I _S (ON)	±0.01		nA typ	V _S = V _D = 1 V, or 4.5 V; see Figure 14
	±0.25	±0.35	nA max	
DIGITAL INPUTS				
Input High Voltage, V _{INH}		2.4	V min	V _{IN} = V _{INL} or V _{INH}
Input Low Voltage, V _{INL}		0.8	V max	
Input Current				
I _{INL} or I _{INH}	0.005		μA typ	
		±0.1	μA max	
DYNAMIC CHARACTERISTICS ¹				
t _{ON}	12		ns typ	R _L = 300 Ω, C _L = 35 pF
		18	ns max	
t _{OFF}	8		ns typ	R _L = 300 Ω, C _L = 35 pF
		12	ns max	
Charge Injection	5		pC typ	V _S = 2 V, R _S = 0 Ω, C _L = 1 nF; see Figure 16
Off Isolation	–55		dB typ	
	–75		dB typ	R _L = 50 Ω, C _L = 5 pF, f = 10 MHz
Bandwidth –3 dB	200		MHz typ	
C _S (OFF)	17		pF typ	R _L = 50 Ω, C _L = 5 pF, f = 1 MHz; see Figure 17
C _D (OFF)	17		pF typ	
C _D , C _S (ON)	38		pF typ	
POWER REQUIREMENTS				
I _{DD}	0.001		μA typ	V _{DD} = 5.5 V
		1.0	μA max	
				Digital inputs = 0 V or 5 V

¹ Guaranteed by design, not subject to production test.

ADG701L/ADG702L

$V_{DD} = 3\text{ V} \pm 10\%$, $GND = 0\text{ V}$. Temperature range for the B version is -40°C to $+85^{\circ}\text{C}$, unless otherwise noted.

Table 2.

Parameter	B Version –40°C to		Unit	Test Conditions/Comments
	+25°C	+85°C		
ANALOG SWITCH				
Analog Signal Range		0 V to V _{DD}	V	
On Resistance (R _{ON})	3.5		Ω typ	V _S = 0 V to V _{DD} , I _S = –10 mA; see Figure 12
	5	6	Ω max	
On Resistance Flatness (R _{FLAT(ON)})	1.5		Ω typ	V _S = 0 V to V _{DD} , I _S = –10 mA
LEAKAGE CURRENTS				
Source Off Leakage I _S (OFF)	±0.01		nA typ	V _{DD} = 3.3 V V _S = 3 V/1 V, V _D = 1 V/3 V; see Figure 13
	±0.25	±0.35	nA max	
Drain Off Leakage I _D (OFF)	±0.01		nA typ	V _S = 3 V/1 V, V _D = 1 V/3 V; see Figure 13
	±0.25	±0.35	nA max	
Channel On Leakage I _D , I _S (ON)	±0.01		nA typ	V _S = V _D = 1 V, or 3 V; see Figure 14
	±0.25	±0.35	nA max	
DIGITAL INPUTS				
Input High Voltage, V _{INH}		2.0	V min	
Input Low Voltage, V _{INL}		0.4	V max	
Input Current I _{INL} or I _{INH}	0.005		μA typ	V _{IN} = V _{INL} or V _{INH}
		±0.1	μA max	
DYNAMIC CHARACTERISTICS ¹				
t _{ON}	14		ns typ	R _L = 300 Ω, C _L = 35 pF
		20	ns max	V _S = 2 V, see Figure 15
t _{OFF}	8		ns typ	R _L = 300 Ω, C _L = 35 pF
		13	ns max	V _S = 2 V, see Figure 15
Charge Injection	4		pC typ	V _S = 1.5 V, R _S = 0 Ω, C _L = 1 nF; see Figure 16
Off Isolation	–55		dB typ	R _L = 50 Ω, C _L = 5 pF, f = 10 MHz
	–75		dB typ	R _L = 50 Ω, C _L = 5 pF, f = 1 MHz; see Figure 17
Bandwidth –3 dB	200		MHz typ	R _L = 50 Ω, C _L = 5 pF; see Figure 18
C _S (OFF)	17		pF typ	
C _D (OFF)	17		pF typ	
C _D , C _S (ON)	38		pF typ	
POWER REQUIREMENTS				
I _{DD}	0.001		μA typ	V _{DD} = 3.3 V Digital Inputs = 0 V or 3 V
		1.0	μA max	

¹ Guaranteed by design, not subject to production test.

ABSOLUTE MAXIMUM RATINGS

$T_A = 25^\circ\text{C}$, unless otherwise noted.

Table 3.

Parameter	Rating
V_{DD} to GND	–0.3 V to +7 V
Analog, Digital Inputs ¹	–0.3 V to $V_{DD} + 0.3$ V or 30 mA, whichever occurs first
Continuous Current, S or D	30 mA
Peak Current, S or D	100 mA, pulsed at 1 ms, 10% duty cycle maximum
Operating Temperature Range	
Industrial (B Version)	–40°C to +85°C
Storage Temperature Range	–65°C to +150°C
Junction Temperature	150°C
MSOP Package, Power Dissipation	315 mW
θ_{JA} Thermal Impedance	206°C/W
θ_{JC} Thermal Impedance	44°C/W
SOT-23 Package, Power Dissipation	282 mW
θ_{JA} Thermal Impedance	229.6°C/W
θ_{JC} Thermal Impedance	91.99°C/W
Lead Temperature, Soldering	
Vapor Phase (60 sec)	215°C
Infrared (15 sec)	220°C
Lead-free Reflow Soldering	
Peak Temperature	260 (+0/–5)°C
Time at Peak Temperature	10 sec to 40 sec
ESD	2 kV

¹ Overvoltages at IN, S, or D are clamped by internal diodes. Current should be limited to the maximum ratings given.

Stresses above those listed under Absolute Maximum Ratings may cause permanent damage to the device. This is a stress rating only; functional operation of the device at these or any other conditions above those indicated in the operational section of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

ESD CAUTION

ESD (electrostatic discharge) sensitive device. Electrostatic charges as high as 4000 V readily accumulate on the human body and test equipment and can discharge without detection. Although this product features proprietary ESD protection circuitry, permanent damage may occur on devices subjected to high energy electrostatic discharges. Therefore, proper ESD precautions are recommended to avoid performance degradation or loss of functionality.



ADG701L/ADG702L

PIN CONFIGURATIONS AND FUNCTION DESCRIPTIONS

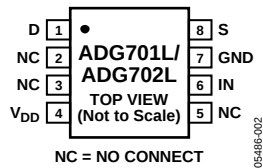


Figure 3. 8-Lead MSOP Pin Configuration

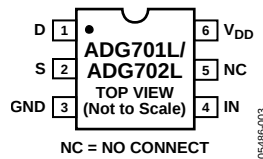


Figure 4. 6-Lead SOT-23 Pin Configuration

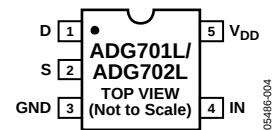


Figure 5. 5-Lead SOT-23 Pin Configuration

Table 4. Pin Function Descriptions

Pin Number			Mnemonic	Description
8-Lead MSOP	6-lead SOT-23	5-lead SOT-23		
1	1	1	D	Drain Terminal. May be an input or output.
2, 3, 5	5	N/A	NC	No Connect.
4	6	5	V _{DD}	Most Positive Power Supply Potential.
6	4	4	IN	Logic Control Input.
7	3	3	GND	Ground (0 V) Reference.
8	2	2	S	Source Terminal. May be an input or output.

Table 5. Truth Table

ADG701L In	ADG702L In	Switch Condition
0	1	Off
1	0	On

TYPICAL PERFORMANCE CHARACTERISTICS

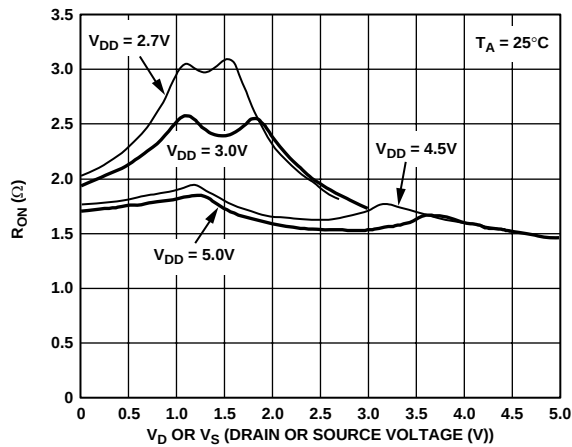


Figure 6. On Resistance as a Function of V_D (V_S) Single Supplies

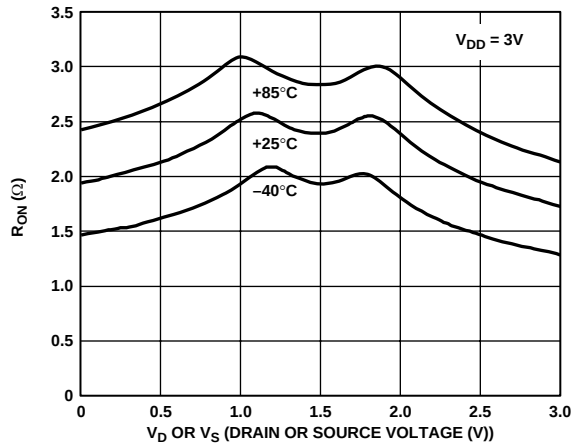


Figure 7. On Resistance as a Function of V_D (V_S) for Different Temperatures $V_{DD} = 3V$

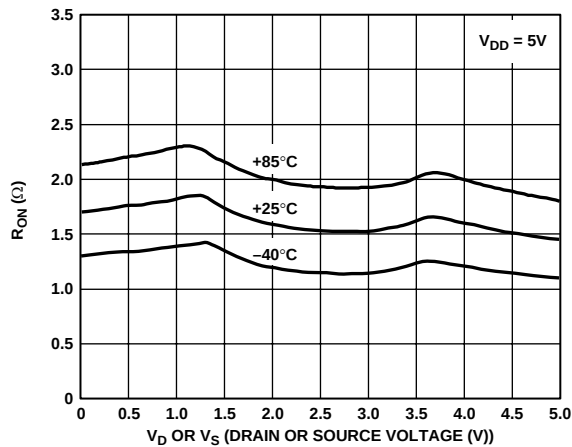


Figure 8. On Resistance as a Function of V_D (V_S) for Different Temperatures $V_{DD} = 5V$

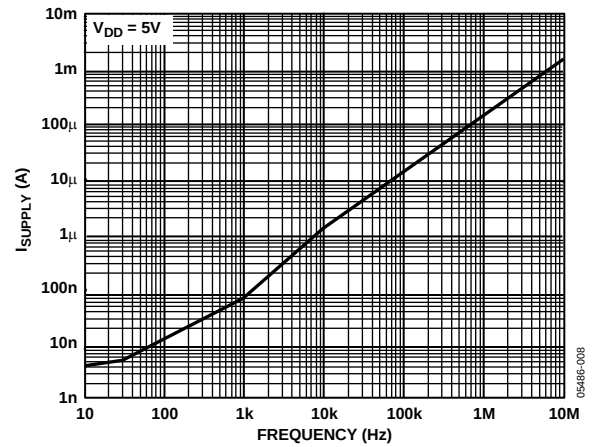


Figure 9. Supply Current vs. Input Switching Frequency

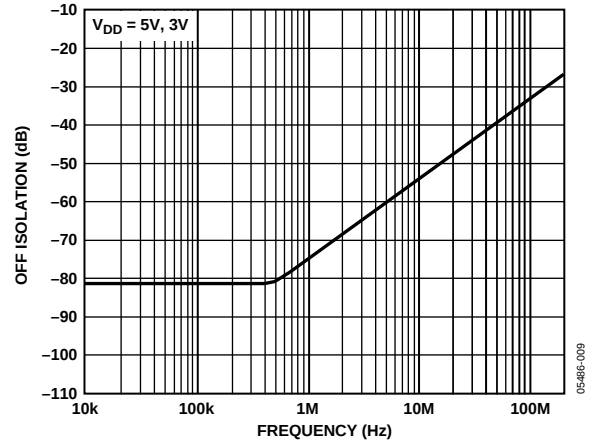


Figure 10. Off Isolation vs. Frequency

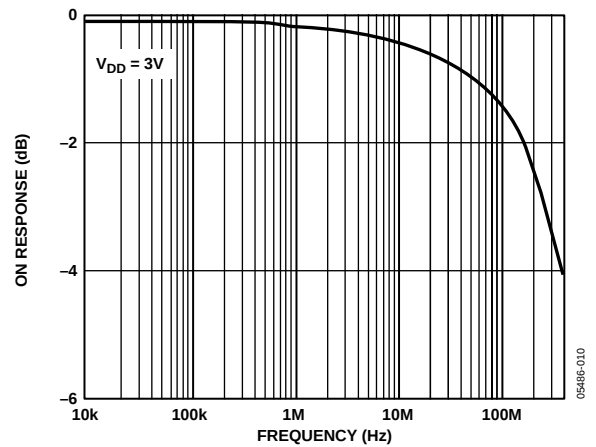
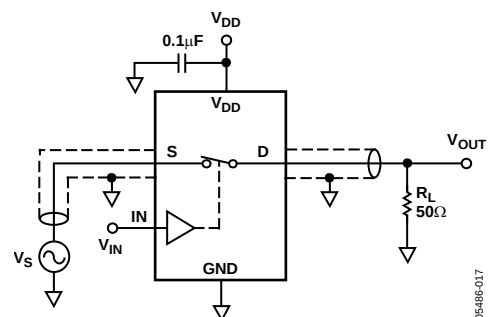
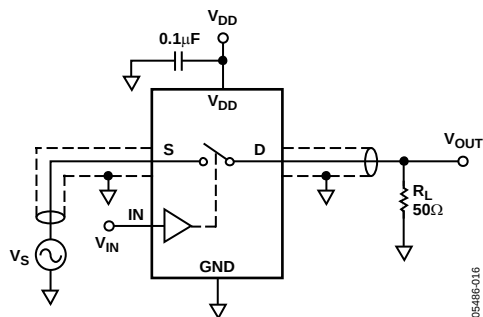
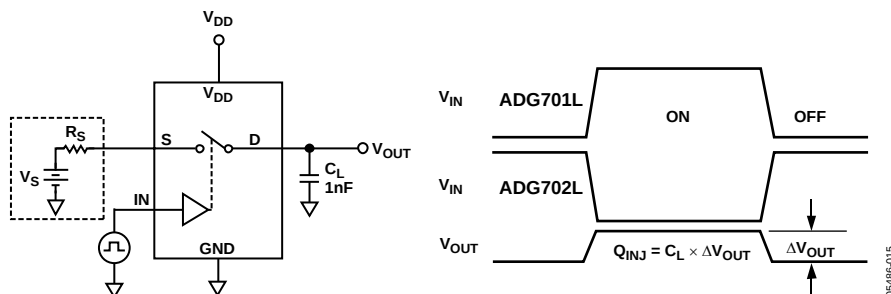
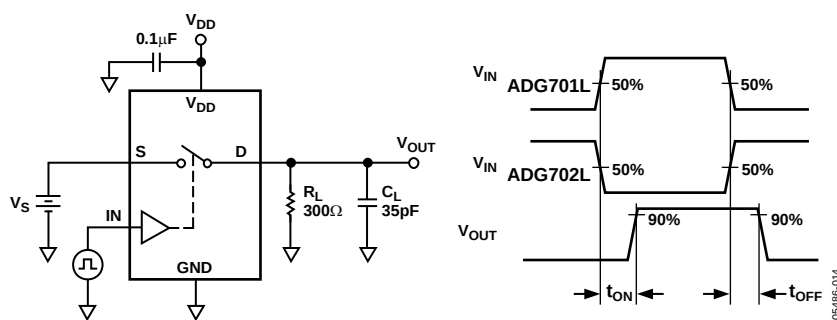
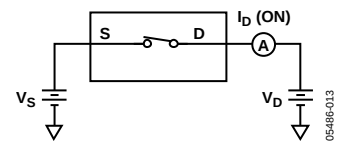
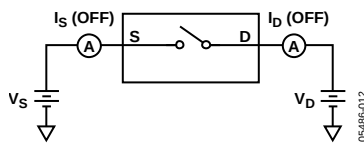
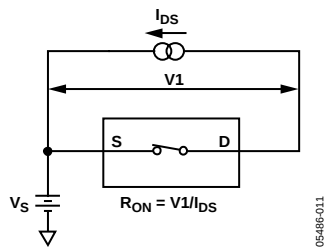


Figure 11. Bandwidth

TEST CIRCUITS



TERMINOLOGY

R_{ON}

Ohmic resistance between D and S.

R_{FLAT (ON)}

Flatness is defined as the difference between the maximum and minimum value of on resistance as measured over the specified analog signal range.

I_S (OFF)

Source leakage current with the switch off.

I_D (OFF)

Drain leakage current with the switch off.

I_D, I_S (ON)

Channel leakage current with the switch on.

V_D (V_S)

Analog voltage on Terminal D and Terminal S.

C_S (OFF)

Off switch source capacitance.

C_D (OFF)

Off switch drain capacitance.

C_D, C_S (ON)

On switch capacitance.

t_{ON}

Delay between applying the digital control input and the output switching on. See Figure 15.

t_{OFF}

Delay between applying the digital control input and the output switching off.

Off Isolation

A measure of unwanted signal coupling through an off switch.

Charge Injection

A measure of the glitch impulse transferred from the digital input to the analog output during switching.

Bandwidth

The frequency at which the output is attenuated by -3 dB.

On Response

The frequency response of the on switch.

On Loss

The voltage drop across the on switch, seen in Figure 11 as the number of decibels the signal is away from 0 dB at very low frequencies.

APPLICATIONS INFORMATION

The ADG701L/ADG702L belong to the Analog Devices new family of CMOS switches. This series of general-purpose switches have improved switching times, lower on resistance, higher bandwidth, low power consumption, and low leakage currents.

SUPPLY VOLTAGES

Functionality of the ADG701L/ADG702L extends from 1.8 V to 5.5 V single supply, making the parts ideal for battery-powered instruments where power, efficiency, and performance are important design parameters.

It is important to note that the supply voltage affects the input signal range, the on resistance, and the switching times of the part. The effects of the power supplies can be clearly seen in the Typical Performance Characteristics and the Specifications sections.

For $V_{DD} = 1.8$ V operation, R_{ON} is typically $40\ \Omega$ over the temperature range.

BANDWIDTH

Figure 19 illustrates the parasitic components that affect the ac performance of CMOS switches (a box surrounds the switch). Additional external capacitances further degrade some performance. These capacitances affect feedthrough, crosstalk, and system bandwidth.

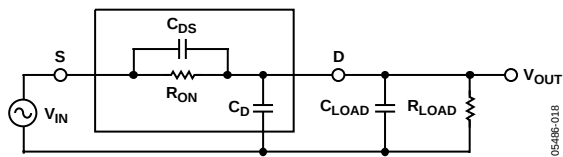


Figure 19. Switch Represented by Equivalent Parasitic Components

The transfer function that describes the equivalent diagram of the switch (see Figure 19) is of the form $A(s)$, as shown in the following equation:

$$A(s) = R_T \left[\frac{s(R_{ON}C_{DS}) + 1}{s(R_{ON}C_T R_T) + 1} \right]$$

where $C_T = C_{LOAD} + C_D + C_{DS}$.

The signal transfer characteristic is dependent on the switch channel capacitance, C_{DS} . This capacitance creates a frequency zero in the numerator of the transfer function, $A(s)$. Because the switch on resistance is small, this zero usually occurs at high frequencies. The bandwidth is a function of the switch output capacitance combined with C_{DS} and the load capacitance. The frequency pole corresponding to these capacitances appears in the denominator of $A(s)$.

The dominant effect of the output capacitance, C_D , causes the pole breakpoint frequency to occur first. In order to maximize bandwidth, a switch must have a low input and output capacitance and low on resistance. The on response versus frequency for the ADG701L/ADG702L is shown in Figure 11.

OFF ISOLATION

Off isolation is a measure of the input signal coupled through an off switch to the switch output. The capacitance, C_{DS} , couples the input signal to the output load when the switch is off (see Figure 20).

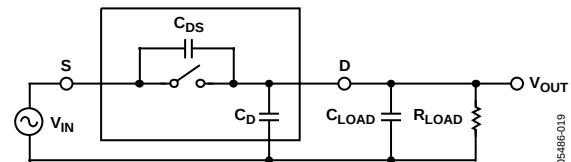


Figure 20. Off Isolation Is Affected by External Load Resistance and Capacitance

The larger the value of C_{DS} , the larger the values of feedthrough produced. Figure 10 illustrates the drop in off isolation as a function of frequency. From dc to roughly 1 MHz, the switch shows better than -75 dB isolation. Up to frequencies of 10 MHz, the off isolation remains better than -55 dB. As the frequency increases, more and more of the input signal is coupled through to the output. Off isolation can be maximized by choosing a switch with the smallest C_{DS} possible. The values of load resistance and capacitance also affect off isolation, as they contribute to the coefficients of the poles and zeros in the transfer function of the switch when open.

$$A(s) = R_T \left[\frac{s(R_{LOAD}C_{DS}) + 1}{s(R_{LOAD})(C_T) + 1} \right]$$

OUTLINE DIMENSIONS

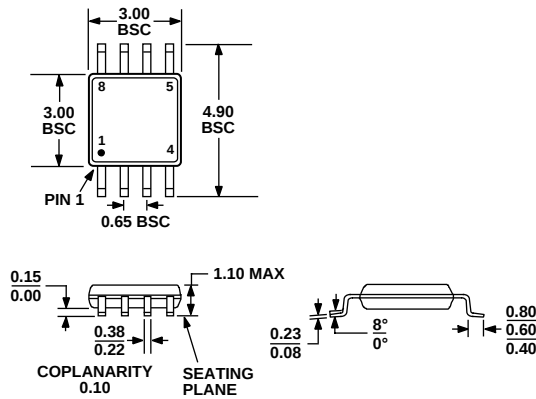


Figure 21. 8-Lead Mini Small Outline Package [MSOP]
(RM-8)

Dimensions shown in millimeters

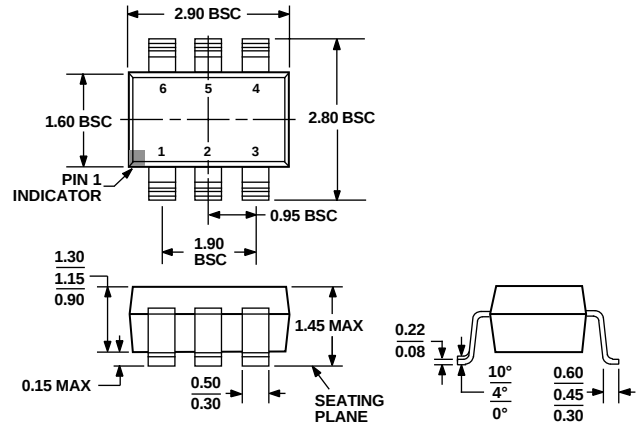


Figure 22. 6-Lead Small Outline Transistor Package [SOT-23]
(RT-6)

Dimensions shown in millimeters

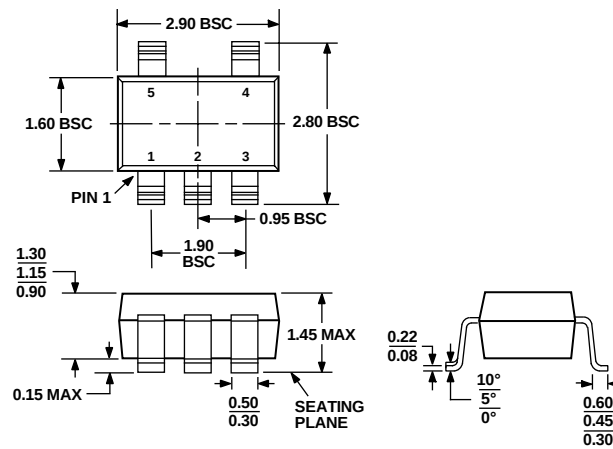


Figure 23. 5-Lead Small Outline Transistor Package [SOT-23]
(RJ-5)

Dimensions shown in millimeters

ADG701L/ADG702L

ORDERING GUIDE

Model	Temperature Range	Package Description	Package Option	Branding ¹
ADG701LBRJ-500RL7	–40°C to +85°C	5-Lead Small Outline Transistor Package [SOT-23]	RJ-5	S15
ADG701LBRJ-REEL	–40°C to +85°C	5-Lead Small Outline Transistor Package [SOT-23]	RJ-5	S15
ADG701LBRJ-REEL7	–40°C to +85°C	5-Lead Small Outline Transistor Package [SOT-23]	RJ-5	S15
ADG701LBRJZ-500RL7 ²	–40°C to +85°C	5-Lead Small Outline Transistor Package [SOT-23]	RJ-5	S10
ADG701LBRJZ-REEL ²	–40°C to +85°C	5-Lead Small Outline Transistor Package [SOT-23]	RJ-5	S10
ADG701LBRJZ-REEL7 ²	–40°C to +85°C	5-Lead Small Outline Transistor Package [SOT-23]	RJ-5	S10
ADG701LBRM	–40°C to +85°C	8-Lead Mini Small Outline Package [MSOP]	RM-8	S15
ADG701LBRM-REEL	–40°C to +85°C	8-Lead Mini Small Outline Package [MSOP]	RM-8	S15
ADG701LBRM-REEL7	–40°C to +85°C	8-Lead Mini Small Outline Package [MSOP]	RM-8	S15
ADG701LBRMZ ²	–40°C to +85°C	8-Lead Mini Small Outline Package [MSOP]	RM-8	S10
ADG701LBRMZ-REEL ²	–40°C to +85°C	8-Lead Mini Small Outline Package [MSOP]	RM-8	S10
ADG701LBRMZ-REEL7 ²	–40°C to +85°C	8-Lead Mini Small Outline Package [MSOP]	RM-8	S10
ADG701LBRT-REEL	–40°C to +85°C	6-Lead Small Outline Transistor Package [SOT-23]	RT-6	S15
ADG701LBRT-REEL7	–40°C to +85°C	6-Lead Small Outline Transistor Package [SOT-23]	RT-6	S15
ADG701LBRTZ-REEL ²	–40°C to +85°C	6-Lead Small Outline Transistor Package [SOT-23]	RT-6	S10
ADG701LBRTZ-REEL7 ²	–40°C to +85°C	6-Lead Small Outline Transistor Package [SOT-23]	RT-6	S10
ADG702LBRJ-REEL	–40°C to +85°C	5-Lead Small Outline Transistor Package [SOT-23]	RJ-5	S16
ADG702LBRJ-REEL7	–40°C to +85°C	5-Lead Small Outline Transistor Package [SOT-23]	RJ-5	S16
ADG702LBRJZ-500RL7 ²	–40°C to +85°C	5-Lead Small Outline Transistor Package [SOT-23]	RJ-5	S11
ADG702LBRJZ-REEL ²	–40°C to +85°C	5-Lead Small Outline Transistor Package [SOT-23]	RJ-5	S11
ADG702LBRJZ-REEL7 ²	–40°C to +85°C	5-Lead Small Outline Transistor Package [SOT-23]	RJ-5	S11
ADG702LBRM	–40°C to +85°C	8-Lead Mini Small Outline Package [MSOP]	RM-8	S16
ADG702LBRM-REEL	–40°C to +85°C	8-Lead Mini Small Outline Package [MSOP]	RM-8	S16
ADG702LBRM-REEL7	–40°C to +85°C	8-Lead Mini Small Outline Package [MSOP]	RM-8	S16
ADG702LBRMZ ²	–40°C to +85°C	8-Lead Mini Small Outline Package [MSOP]	RM-8	S11
ADG702LBRMZ-REEL ²	–40°C to +85°C	8-Lead Mini Small Outline Package [MSOP]	RM-8	S11
ADG702LBRMZ-REEL7 ²	–40°C to +85°C	8-Lead Mini Small Outline Package [MSOP]	RM-8	S11
ADG702LBRT-REEL	–40°C to +85°C	6-Lead Small Outline Transistor Package [SOT-23]	RT-6	S16
ADG702LBRT-REEL7	–40°C to +85°C	6-Lead Small Outline Transistor Package [SOT-23]	RT-6	S16
ADG702LBRTZ-REEL ²	–40°C to +85°C	6-Lead Small Outline Transistor Package [SOT-23]	RT-6	S11
ADG702LBRTZ-REEL7 ²	–40°C to +85°C	6-Lead Small Outline Transistor Package [SOT-23]	RT-6	S11

¹ Due to package size limitations, these three characters represent the part number.

² Z = Pb-free part.